

# Hyperfast Soft Recovery Diode, 60 A FRED Pt<sup>®</sup> Gen 4



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	60 A					
$V_{R}$	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.48 V					
t <sub>rr</sub> typ.	see Recovery table					
T <sub>J</sub> max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

#### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RRM</sub> and reverse recovery charge
- · Very low forward voltage drop
- Polyimide passivated chip for high reliability standard



- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	$V_{R}$		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 106 °C	60	۸			
Single pulse forward current	I <sub>FSM</sub>	$T_C$ = 25 °C, $t_p$ = 8.3 ms, half sine wave	425	А			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage		I <sub>F</sub> = 50 A	-	1.68	-	V	
	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	1.75	2.0		
		I <sub>F</sub> = 50 A, T <sub>J</sub> = 125 °C	-	1.44	-		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.55	-		
		I <sub>F</sub> = 50 A, T <sub>J</sub> = 150 °C	-	1.39	-		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	1.65		
Developed to the comment	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	50		
Reverse leakage current		T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	500	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	30	-	pF	



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Poverse receivery time	+	T <sub>J</sub> = 25 °C		-	68	-	ns	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	$I_F = 60 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	92	-		
Dook roopyon, gurrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	20	-	A	
Peak recovery current		T <sub>J</sub> = 125 °C		-	40	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	945	-	nC	
		T <sub>J</sub> = 125 °C		-	2500	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.6			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.25	-			
Waisht			-	6.0	-	g		
Weight			-	0.21	-	oz.		
Mounting torque			6.0 (5)	-	12 (20)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 2L	E4PH6006L					

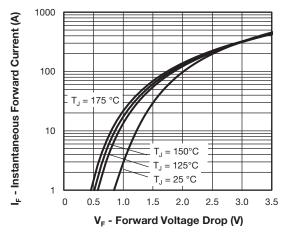


Fig. 1 - Typical Forward Voltage Drop Characteristics

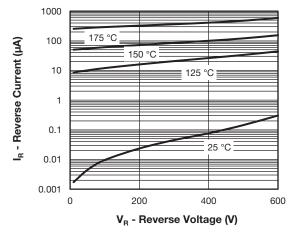


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

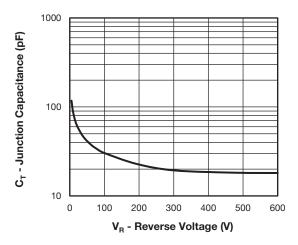


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

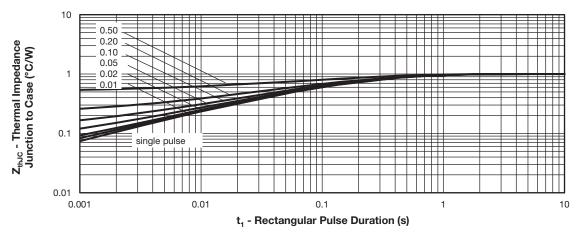


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

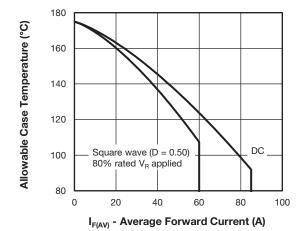


Fig. 5 - Max. Allowable Case Temperature vs. Average Forward Current

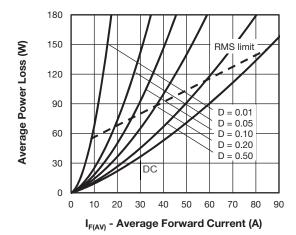


Fig. 6 - Forward Power Loss Characteristics

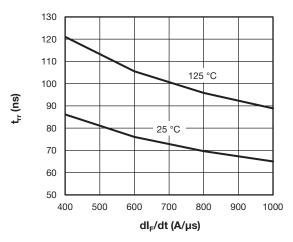
#### Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see Fig.5)} \\ P_{dREV} = \text{inverse power loss} = V_{R1} \times I_R \ \text{(1 - D); } I_R \ \text{at } V_R = \text{rated } V_R \\ \end{array}$ 



#### www.vishay.com

# Vishay Semiconductors



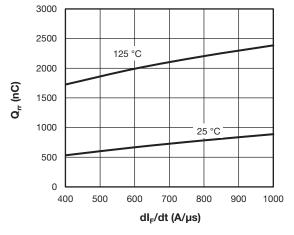


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

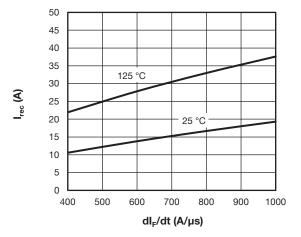
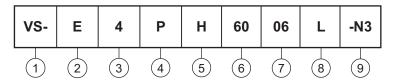


Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt



### **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors product
- Circuit configuration:

E = single diode 2 pins

- 3 FRED Gen 4
- P = TO-247 package
- 5 Process type:

H = hyperfast recovery

- 6 Current rating (60 = 60 A)
- 7 Voltage rating (06 = 600 V)
- 8 L = long lead
- 9 Environmental digit:

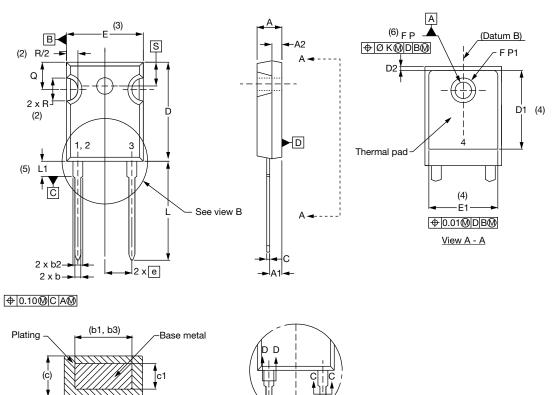
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E4PH6006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95536</u>					
Part marking information	www.vishay.com/doc?95648				

### **TO-247AD 2L**

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	IETERS INCHES		NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	INCHES		
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Е	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØK	0.2	0.254		10		
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217 BSC			
	•		•	•		

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.